

राष्ट्रीय प्रौद्योगि की संस्थान सिलचर National Institute of Technology Silchar

(राष्ट्रीयमहत्वकासंस्थान)

(An Institute of National Importance)

www.nits.ac.in, Phone: 03842-242914, Fax: 03842-224797, Assam-788010 (INDIA)

Advertisement No.: NITS/Dean(R&C)/ME/701/01/2025

Date: 02.09.2025

Applications are invited from Indian citizens for a temporary of post of **Junior Research Fellow** for the **ANRF** sponsored project in the Department of Mechanical Engineering, NIT Silchar.

Title of the project	Development of Fast Fault Detection and Location Estimation Scheme for				
	Low-Voltage DC Microgrids				
Sponsored Agency	Anusandhan National Research Foundation (ANRF)				
Project sanction number	ANRF/ECRG/2024/006246/ENS				
No. of posts	One (01)				
Duration	Three (03) years (extension based on performance review every 12 months)				
Principal Investigator (P.I)	Dr. Biswajit Sahoo, Assistant professor, Department of Electrical				
	Engineering, National Institute of Technology Silchar, Assam-788010.				

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Gen	eral Information and Terms &	Conditions
1.	Age Limit	35 years (as on the closing date of application, 19.09.2025)
2.	Essential Qualification	 (i) B.E./ B. Tech or equivalent degree in Electrical Engineering/ Electrical and Electronics Engineering (ii) M.E./ M. Tech or equivalent degree in Electrical Engineering/ Electrical and Electronics Engineering (GATE qualified students will be given preference)
3.	Desirable Experience	 (i) Basic knowledge in Power System Protection. (ii) Prior knowledge of Microgrid Dynamics and Control, Renewables (i.e. Solar PV), Power Electronics Converters, AI/ML Algorithms is advantageous but not mandatory.
4.	Salary	Rs. 37,000/- p.m. for first two years (JRF); Rs. 42000/- p.m. for third year (SRF) (for candidates with GATE qualification) Rs. 30,000/-p.m. for first two years (JRF); Rs. 35000/- p.m. for third year (SRF) (for candidates without GATE qualification) HRA @9% if Institute Accommodation is not provided.
5.	Relaxation on qualification and age	SC/ST/OBC/WOMEN/PWD candidates will get relaxation as per Govt of India Rules.
6.	Č	19 th September 2025
7.	Reporting	Applicants are requested to submit their filled-up applications along with C.V. to the P.I. accompanying photocopies of all documents. Applicants are also requested to send the soft copy of the duly filled application along with C.V. & all necessary documents to the P.I through email: biswajitsahoo@ee.nits.ac.in
8.	Date of interview, time, and venue	Date, time and venue will be notified to shortlisted candidates.
9.	No objection certificate	Employed candidates are to submit no objection certificate from his/her employer at the time of interview.
10.	Institute right	The Institute has the discretion to restrict the number of candidates to be called for the interview on the basis of screening. No candidate may be recruited if suitable candidates are not found.
11.	Signing of the agreement	Selected candidates shall have to sign an agreement at the time of joining.

Sd/-

Associate Dean (R&C)

NIT Silchar.

National Institute of Technology Silchar FORMAT of APPLICATION

For Junior Research Fellow

Paste recent passport size colored photograph

1.	Advertisement no
2.	Title of the Project-
3.	Department:
4.	Name of the applicant(in block letters):
5.	Father's/Husband's Name:
6.	Date of Birth (DD-MM-YYYY):
7.	Age as on 19.09.2025 :
8.	Postal Address:
	E-mail: Phone no.:
9.	Permanent Address:
10.	Nationality:
11.	Marital Status:
12.	Whether belongs to SC/ST/PwD/OBC/EWS:(If yes, attach certificate):

Exam. passe d	Board/University	Division	% age of marks/ CPI	Year of passing	Subjects

13. Educational Qualification:(Starting from Class X)

14. NET/GATE Examinations Passed:

I. NET			I	I. GATE	Ţ.
Subject	Qualifying date	Valid up to	Subject	Score	Valid up to

15. Details of employments:

Sl. No.	Name of the Organization	Name of the post	Period	Scale of pay and present pay	Nature of duty

Decl	laration
I declare that the above information are true and co	orrect to the best of my knowledge and belief.
Date:	
Place	Signature of the applicant